

FEATURES

- * 0.7INCH (17.22mm) DIGIT HEIGHT.
- * CONTINUOUS UNIFORM SEGMENTS.
- * LOW POWER REQUIREMENT.
- * EXCELLENT CHARACTERS APPEARANCE.
- * HIGH BRIGHTNESS & HIGH CONTRAST.
- * WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- * CATEGORIZED FOR LUMINOUS INTENSITY.

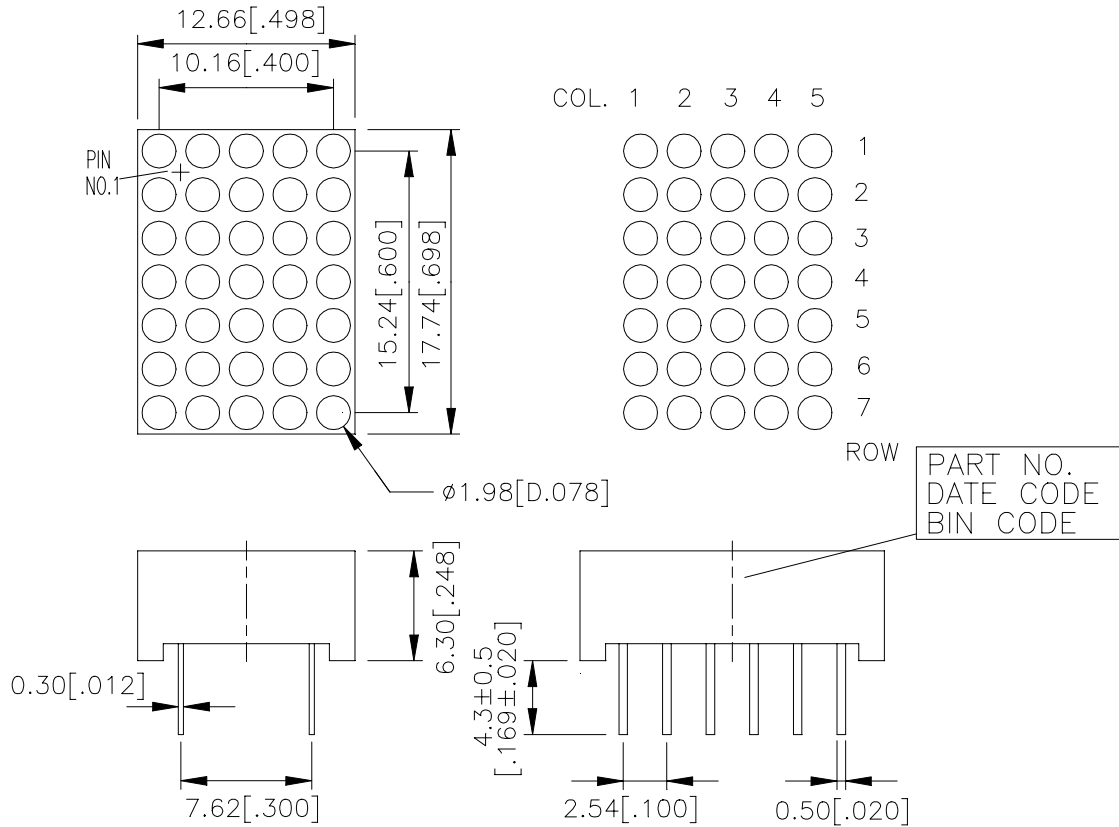
DESCRIPTION

The LTP-747KY is a 0.7inch (17.22mm) matrix height 5 x 7 dot matrix display. This device utilizes AllnGap Amber Yellow LED chips, which are made from AllnGaP on a non-transparent GaAs substrate, and has a gray face and white dots.

DEVICE

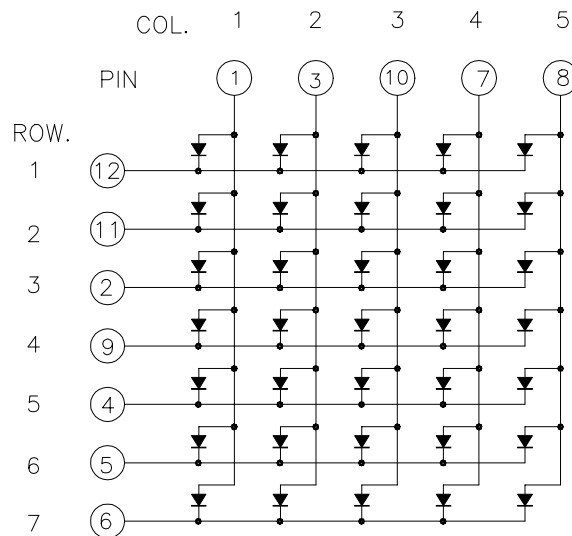
| PART NO. | DESCRIPTION |
|----------------------|--------------------|
| AllnGaP AMBER YELLOW | Anode Column |
| LTP-747KY | Cathode Row |

PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 -mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

| No. | CONNECTION |
|------------|-------------------|
| 1 | ANODE COLUMN 1 |
| 2 | CATHODE ROW 3 |
| 3 | ANODE COLUMN 2 |
| 4 | CATHODE ROW 5 |
| 5 | CATHODE ROW 6 |
| 6 | CATHODE ROW 7 |
| 7 | ANODE COLUMN 4 |
| 8 | ANODE COLUMN 5 |
| 9 | CATHODE ROW 4 |
| 10 | ANODE COLUMN 3 |
| 11 | CATHODE ROW 2 |
| 12 | CATHODE ROW 1 |

ABSOLUTE MAXIMUM RATING AT T_A=25°C

| PARAMETER | MAXIMUM RATING | UNIT |
|---|----------------|-------|
| Average Power Dissipation Per dot | 25 | mW |
| Peak Forward Current Per dot | 60 | mA |
| Average Forward Current Per dot | 13 | mA |
| Derating Linear From 25°C Per dot | 0.17 | mA/°C |
| Reverse Voltage Per dot | 5 | V |
| Operating Temperature Range | -35°C to +85°C | |
| Storage Temperature Range | -35°C to +85°C | |
| Solder Temperature 1/16 inch Below Seating Plane for 3 Seconds at 260°C | | |

ELECTRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | TEST CONDITION |
|-----------------------------------|-------------------|------|------|------|------|---------------------------------|
| Average Luminous Intensity | I _v | 1650 | 3400 | | μcd | I _F =32mA , 1/16Duty |
| Peak Emission Wavelength | λ _p | | 595 | | nm | I _F =20mA |
| Spectral Line Half-Width | Δλ | | 15 | | nm | I _F =20mA |
| Dominant Wavelength | λ _d | | 592 | | nm | I _F =20mA |
| Forward Voltage Per dot | V _F | | 2.05 | 2.6 | V | I _F =20mA |
| Reverse Current Per dot | I _R | | | 100 | μA | V _R =5V |
| Luminous Intensity Matching Ratio | I _v -m | | | 2:1 | | I _F =32mA , 1/16Duty |

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

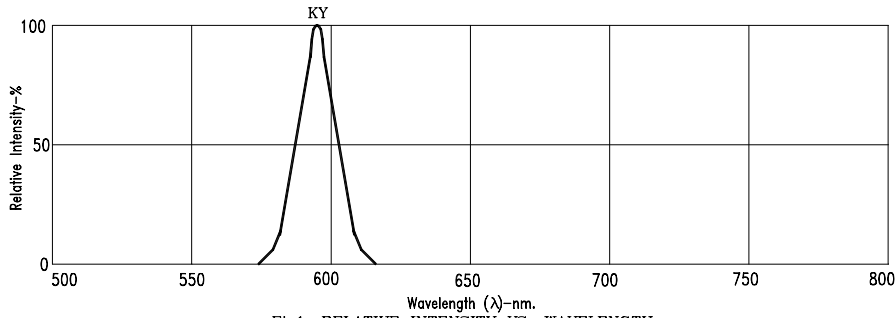


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

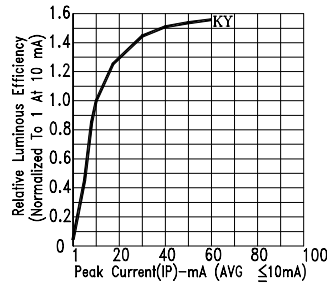


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT

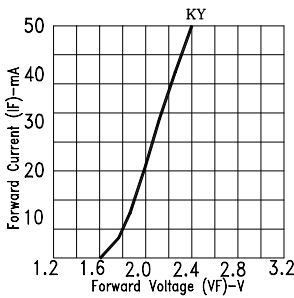


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

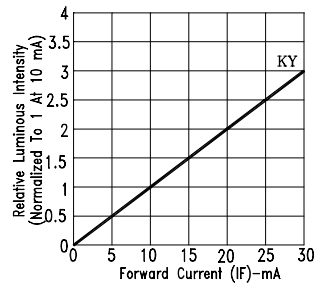


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

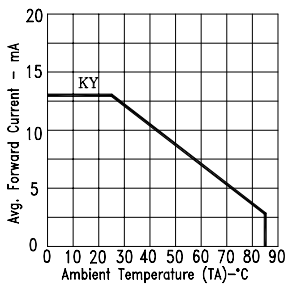


Fig5. MAX. AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

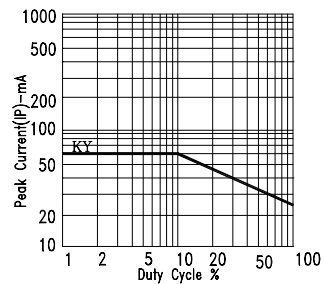


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: KY=AlInGaP AMBER YELLOW